



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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NID5001N

Self-Protected FET with Temperature and Current Limit

HDPlus devices are an advanced series of power MOSFETs which utilize ON Semiconductor's latest MOSFET technology process to achieve the lowest possible on-resistance per silicon area while incorporating smart features. Integrated thermal and current limits work together to provide short circuit protection. The devices feature an integrated Drain-to-Gate Clamp that enables them to withstand high energy in the avalanche mode. The Clamp also provides additional safety margin against unexpected voltage transients. Electrostatic Discharge (ESD) protection is provided by an integrated Gate-to-Source Clamp.

Features

- Low $R_{DS(on)}$
- Current Limitation
- Thermal Shutdown with Automatic Restart
- Short Circuit Protection
- I_{DSS} Specified at Elevated Temperature
- Avalanche Energy Specified
- Slew Rate Control for Low Noise Switching
- Overvoltage Clamped Protection
- Pb-Free Package is Available

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage Internally Clamped	V_{DSS}	42	Vdc
Drain-to-Gate Voltage Internally Clamped ($R_{GS} = 1.0\text{ M}\Omega$)	V_{DGR}	42	Vdc
Gate-to-Source Voltage	V_{GS}	± 14	Vdc
Drain Current – Continuous	I_D	Internally Limited	
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 1) @ $T_A = 25^\circ\text{C}$ (Note 1) @ $T_A = 25^\circ\text{C}$ (Note 2)	P_D	64 1.0 1.56	W
Thermal Resistance, Junction-to-Case Junction-to-Ambient (Note 1) Junction-to-Ambient (Note 2)	$R_{\theta JC}$ $R_{\theta JA}$ $R_{\theta JA}$	1.95 120 80	$^\circ\text{C/W}$
Single Pulse Drain-to-Source Avalanche Energy ($V_{DD} = 25\text{ Vdc}$, $V_{GS} = 5.0\text{ Vdc}$, $I_L = 4.5\text{ Apk}$, $L = 120\text{ mH}$, $R_G = 25\ \Omega$)	E_{AS}	1215	mJ
Operating and Storage Temperature Range	T_J , T_{stg}	-55 to 150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Minimum FR4 PCB, steady state.
2. Mounted onto a 2" square FR4 board (1" square, 2 oz. Cu 0.06" thick single-sided, $t = \text{steady state}$).

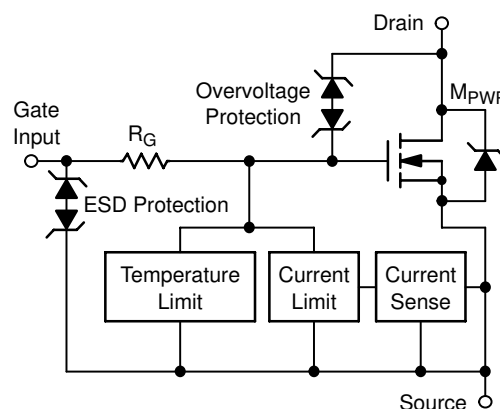


ON Semiconductor®

<http://onsemi.com>

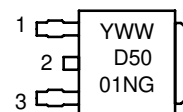
V_{DSS} (Clamped)	$R_{DS(on)}$ TYP	I_D MAX (Limited)
42 V	23 m Ω @ 10 V	33 A*

*Max current may be limited below this value depending on input conditions.



DPAK
CASE 369C
STYLE 2

MARKING DIAGRAM



Y = Year
WW = Work Week
D5001N = Device Code
G = Pb-Free Package
1 = Gate
2 = Drain
3 = Source

ORDERING INFORMATION

Device	Package	Shipping†
NID5001NT4	DPAK	2500/Tape & Reel
NID5001NT4G	DPAK (Pb-Free)	2500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NID5001N

MOSFET ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Clamped Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 250 μAdc) (V _{GS} = 0 Vdc, I _D = 250 μAdc, T _J = 150°C)	V _{(BR)DSS}	42 42	46 44	50 50	Vdc	
Zero Gate Voltage Drain Current (V _{DS} = 32 Vdc, V _{GS} = 0 Vdc) (V _{DS} = 32 Vdc, V _{GS} = 0 Vdc, T _J = 150°C)	I _{DSS}		1.5 6.5	5.0	μAdc	
Gate Input Current (V _{GS} = 5.0 Vdc, V _{DS} = 0 Vdc)	I _{GSSF}		50	100	μAdc	
ON CHARACTERISTICS						
Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 1.2 mAdc) Threshold Temperature Coefficient	V _{GS(th)}	1.0	1.8 5.0	2.0	Vdc -mV/°C	
Static Drain-to-Source On-Resistance (Note 3) (V _{GS} = 10 Vdc, I _D = 5.0 Adc, T _J @ 25°C) (V _{GS} = 10 Vdc, I _D = 5.0 Adc, T _J @ 150°C)	R _{DS(on)}		23 43	29 55	mΩ	
Static Drain-to-Source On-Resistance (Note 3) (V _{GS} = 5.0 Vdc, I _D = 5.0 Adc, T _J @ 25°C) (V _{GS} = 5.0 Vdc, I _D = 5.0 Adc, T _J @ 150°C)	R _{DS(on)}		28 50	34 60	mΩ	
Source-Drain Forward On Voltage (I _S = 5 A, V _{GS} = 0 V)	V _{SD}		0.80	1.1	V	
SWITCHING CHARACTERISTICS						
Turn-on Time	V _{GS} = 5.0 Vdc, V _{DD} = 25 Vdc I _D = 1.0 Adc, Ext R _G = 2.5 Ω	T _(on)		32	40	μs
Turn-off Time		T _(off)		68	75	
Turn-on Time	V _{GS} = 10 Vdc, V _{DD} = 25 Vdc, I _D = 1.0 Adc, Ext R _G = 2.5 Ω	T _(on)		11	15	
Turn-off Time		T _(off)		86	95	
Slew Rate On	R _L = 4.7 Ω, V _{in} = 0 to 10 V, V _{DD} = 12 V	-dV _{DS} /dt _{on}		0.5		V/μs
Slew-Rate Off	R _L = 4.7 Ω, V _{in} = 10 to 0 V, V _{DD} = 12 V	dV _{DS} /dt _{off}		0.35		V/μs
SELF PROTECTION CHARACTERISTICS (T_J = 25°C unless otherwise noted)						
Current Limit	(V _{GS} = 5.0 Vdc) V _{DS} = 10 V (V _{GS} = 5.0 Vdc, T _J = 150°C)	I _{LIM}	21	30	36	Adc
	(V _{GS} = 10 Vdc) V _{DS} = 10 V (V _{GS} = 10 Vdc, T _J = 150°C)		12	19	30	
			29	41	49	
			13	24	31	
Temperature Limit (Turn-off)	V _{GS} = 5.0 Vdc	T _{LIM(off)}	150	175	200	°C
Temperature Limit (Circuit Reset)	V _{GS} = 5.0 Vdc	T _{LIM(on)}	135	160	185	°C
Temperature Limit (Turn-off)	V _{GS} = 10 Vdc	T _{LIM(off)}	150	165	185	°C
Temperature Limit (Circuit Reset)	V _{GS} = 10 Vdc	T _{LIM(on)}	135	150	170	°C
ESD ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)						
Electro-Static Discharge Capability Human Body Model (HBM) Machine Model (MM)	ESD		4000 400			V

3. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

TYPICAL PERFORMANCE CURVES

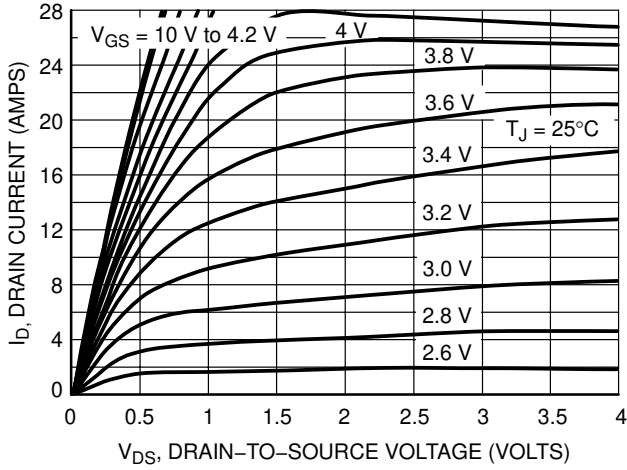


Figure 1. On-Region Characteristics

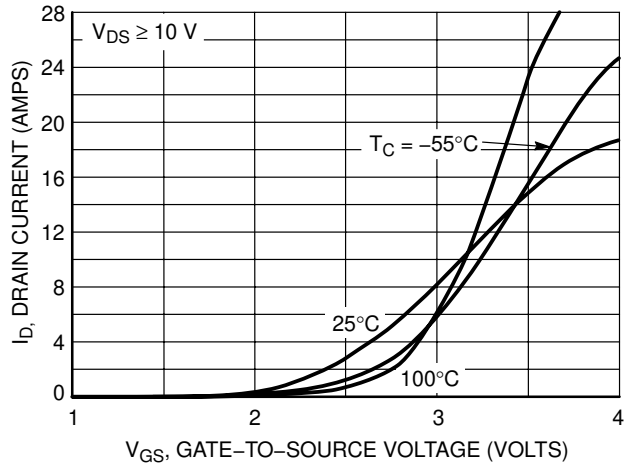


Figure 2. Transfer Characteristics

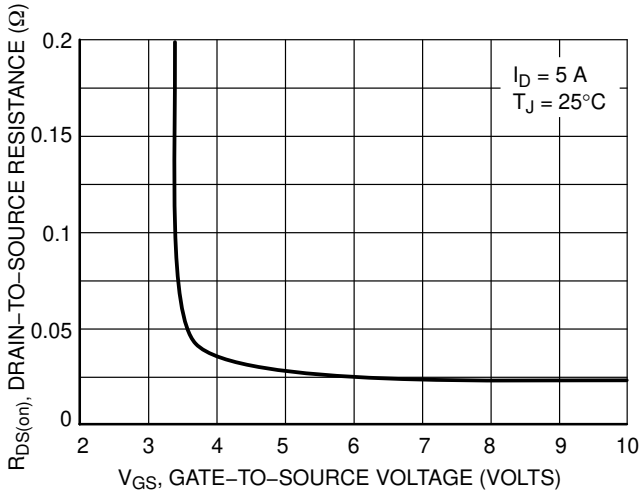


Figure 3. On-Resistance vs. Gate-to-Source Voltage

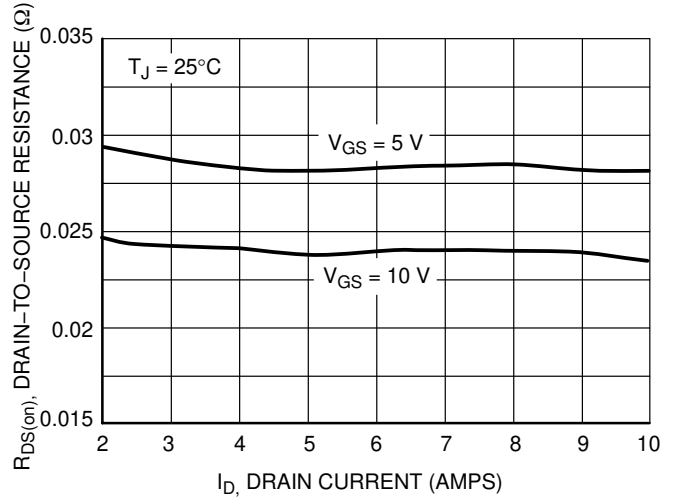


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

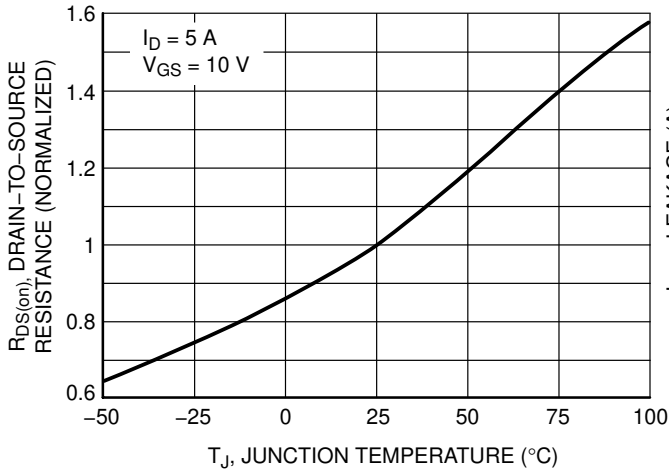


Figure 5. On-Resistance Variation with Temperature

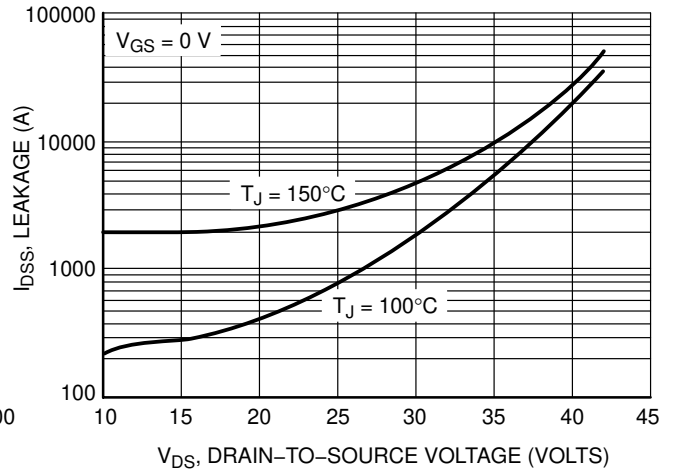


Figure 6. Drain-to-Source Leakage Current vs. Voltage

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TYPICAL PERFORMANCE CURVES

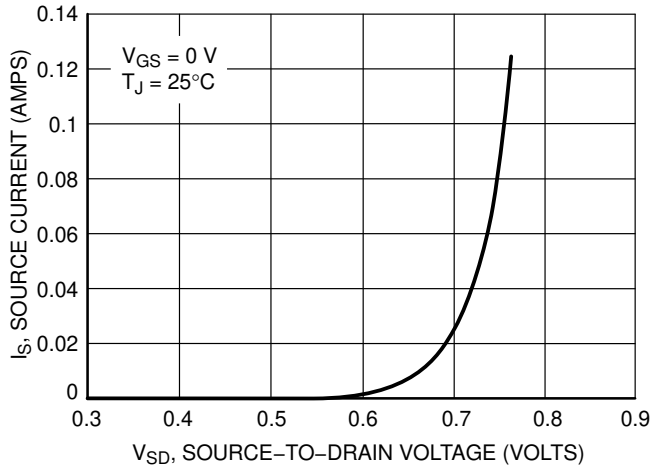


Figure 7. Diode Forward Voltage vs. Current

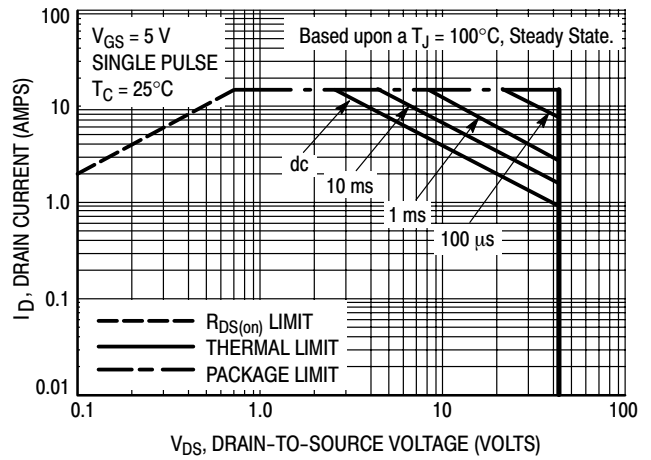
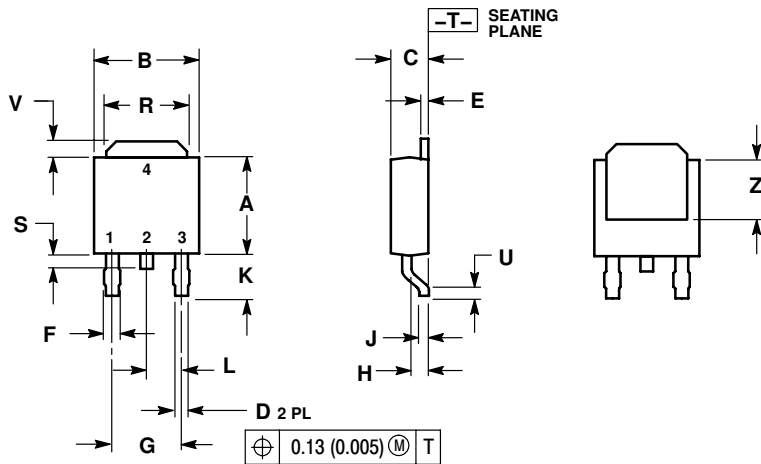


Figure 8. Maximum Rated Forward Biased Safe Operating Area

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PACKAGE DIMENSIONS

DPAK
CASE 369C-01
ISSUE O

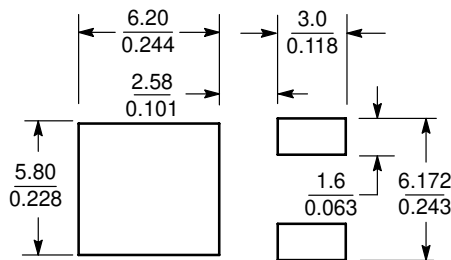


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020	----	0.51	----
V	0.035	0.050	0.89	1.27
Z	0.155	----	3.93	----

- STYLE 2:
 PIN 1. GATE
 2. DRAIN
 3. SOURCE
 4. DRAIN

SOLDERING FOOTPRINT*



SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}} \right)$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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